



DMN32D2LDF

COMMON SOURCE DUAL N-CHANNEL ENHANCEMENT MODE FIELD EFFECT TRANSISTOR

Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0

Terminals: Finish – Matte Tin annealed over Alloy 42 leadframe. Solderable per MIL-STD-202, Method 208

Moisture Sensitivity: Level 1 per J-STD-020C

Terminal Connections: See Diagram

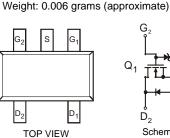
Marking Information: See Page 3

Ordering Information: See Page 3

Features

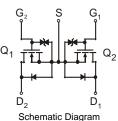
- Common Source Dual N-Channel MOSFET
- Low On-Resistance
- Very Low Gate Threshold Voltage, 1.2V max
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Small Surface Mount Package
- **ESD** Protected Gate
- Lead Free By Design/RoHS Compliant (Note 2)
- "Green" Device (Note 3)
- Qualified to AEC-Q 101 Standards for High Reliability

BOTTOM VIEW



Mechanical Data

Case: SOT-353



Maximum Ratings Q_1, Q_2 @T_A = 25°C unless otherwise specified

TOP VIEW

Characteristic	Symbol	Value	Unit
Drain Source Voltage	V _{DSS}	30	V
Gate-Source Voltage	V _{GSS}	±10	V
Drain Current (Note 1)	ID	400	mA

SOT-353

Thermal Characteristics Q_1, Q_2 @T_A = 25°C unless otherwise specified

Total Power Dissipation (Note 1)	PD	280	mW
Thermal Resistance, Junction to Ambient (Note 1)	$R_{ ext{ heta}JA}$	446	°C/W
Operating and Storage Temperature Range	T _j , T _{STG}	-55 to +150	°C

Electrical Characteristics Q_1, Q_2 @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 4)		- I I					
Drain-Source Breakdown Voltage		BV _{DSS}	30	_		V	$V_{GS} = 0V, I_D = 250 \mu A$
Zero Gate Voltage Drain Current	@ T _C = 25°C	I _{DSS}	_		1	μA	$V_{DS} = 30V, V_{GS} = 0V$
Gate-Body Leakage			_	_	±10 ±1	μA	$V_{GS} = \pm 10V, V_{DS} = 0V$ $V_{GS} = \pm 5V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 4)							
Gate Threshold Voltage			0.6	_	1.2	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$
			_	_	2.2		$V_{GS} = 1.8V, I_D = 20mA$
Static Drain-Source On-Resistance		R _{DS} (ON)	—	—	1.5	Ω	$V_{GS} = 2.5V, I_D = 20mA$
			_	_	1.2		$V_{GS} = 4.0V, I_D = 100mA$
Forward Transconductance			100	_	—	mS	$V_{DS} = 10V, I_D = 0.1A$
Source-Drain Diode Forward Voltage			0.5	_	1.4	V	$V_{GS} = 0V, I_{S} = 115mA$
DYNAMIC CHARACTERISTICS							
Input Capacitance			_	39		pF	
Output Capacitance			_	10		pF	V _{DS} = 3V, V _{GS} = 0V f = 1.0MHz
Reverse Transfer Capacitance				3.6		pF	
Switching Time	Turn-on Time	t _{on}	_	11		nS	$V_{DD} = 5V, I_D = 10 \text{ mA},$
Switching Time	Turn-off Time	t _{off}		51		nS	V _{GS} = 0-5V

1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which Notes: can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

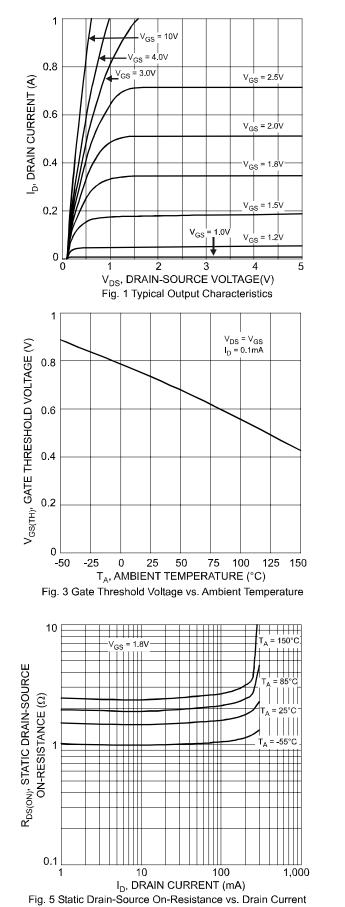
2 No purposefully added lead.

Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php. 3.

4. Short duration pulse test used to minimize self-heating effect.



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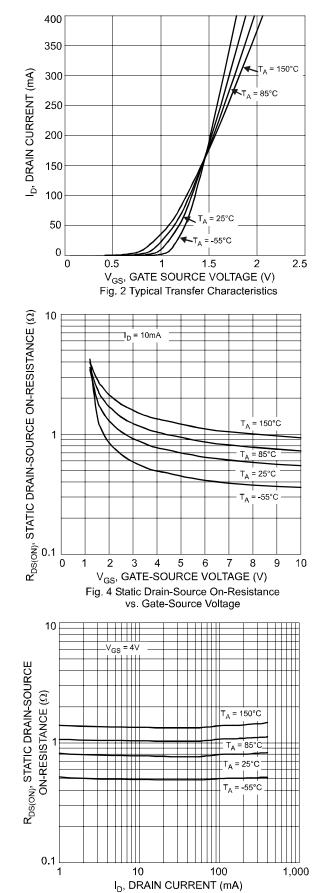


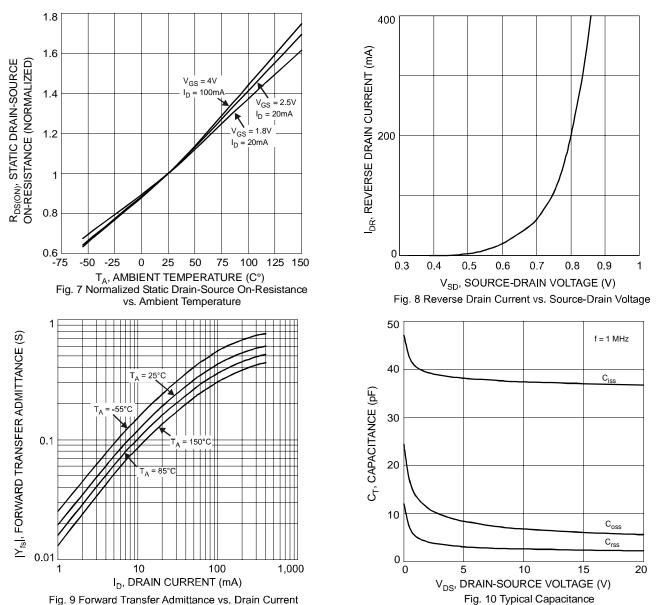
Fig. 6 Static Drain-Source On-Resistance vs. Drain Current

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NEW PRODUCT

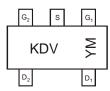


Ordering Information (Note 5)

Part Number	Case	Packaging
DMN32D2LDF-7	SOT-353	3000/Tape & Reel

Notes: 5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information (Note 6)



 $\begin{array}{l} \mathsf{KDV} = \mathsf{Product} \ \mathsf{Type} \ \mathsf{Marking} \ \mathsf{Code} \ (\mathsf{See} \ \mathsf{Note} \ 6) \\ \mathsf{YM} = \mathsf{Date} \ \mathsf{Code} \ \mathsf{Marking} \\ \mathsf{Y} = \mathsf{Year} \ \mathsf{ex:} \ \mathsf{U} = 2007 \\ \mathsf{M} = \mathsf{Month} \ \mathsf{ex:} \ 9 = \mathsf{September} \end{array}$

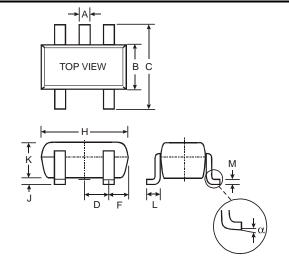
Notes: 6. Package is non-polarized. Parts may be on reel in orientation illustrated, 180° rotated, or mixed (both ways).

Date Code Key

Year	20	07	20	08	20	09	20	10	20	11	20	12
Code	ι	J	١	/	٧	V)	<	١	(Z	2
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	Ν	D

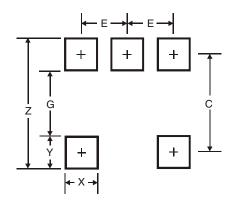


Package Outline Dimensions



SOT-353				
Dim	Min	Max		
Α	0.10	0.30		
В	1.15	1.35		
С	2.00	2.20		
D	0.65 Nominal			
F	0.30	0.40		
Н	1.80	2.20		
J	_	0.10		
κ	0.90	1.00		
L	0.25	0.40		
Μ	0.10	0.25		
α	0°	8°		
All Di	mensions	in mm		

Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.5
G	1.3
Х	0.42
Y	0.6
С	1.9
E	0.65

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